

## TC74VHC574F, TC74VHC574FT, TC74VHC574FK

### Octal D-Type Flip Flop with 3-State Output

The TC74VHC574 is advanced high speed CMOS OCTAL FLIP-FLOP with 3-STATE OUTPUT fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

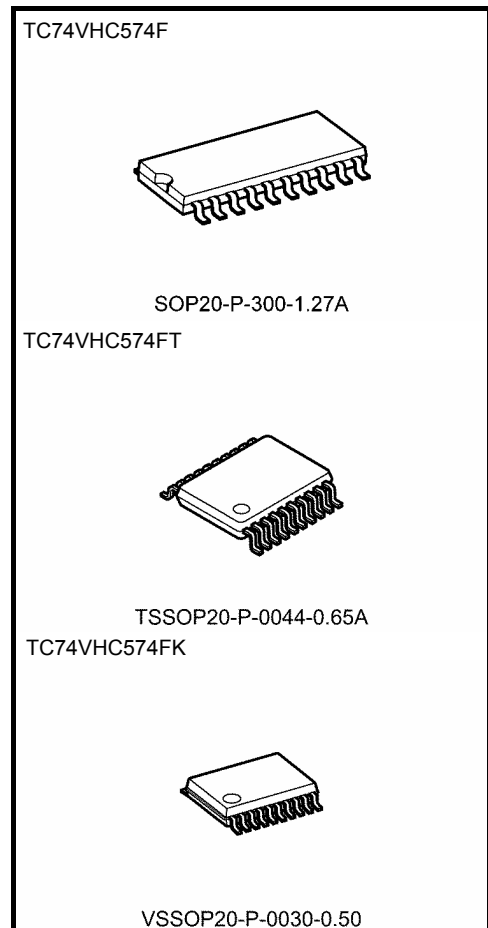
This 8-bit D-type flip-flop is controlled by a clock input (CK) and an output enable input ( $\overline{OE}$ ).

When the  $\overline{OE}$  input is high, the eight outputs are in a high impedance state.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

### Features

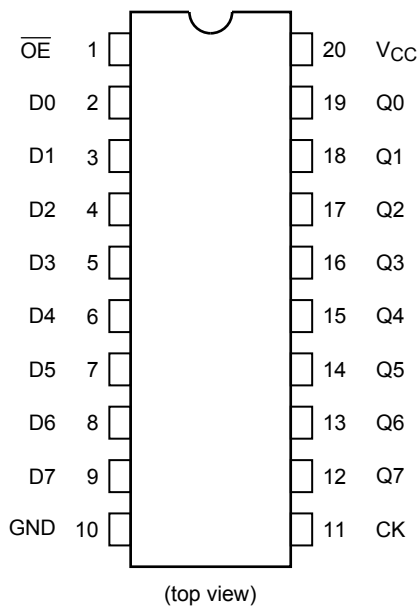
- High speed:  $f_{max} = 180$  MHz (typ.) at  $V_{CC} = 5$  V
- Low power dissipation:  $I_{CC} = 4$   $\mu$ A (max) at  $T_a = 25^\circ\text{C}$
- High noise immunity:  $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays:  $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range:  $V_{CC} (opr) = 2$  to  $5.5$  V
- Low noise:  $V_{OLP} = 1.2$  V (max)
- Pin and function compatible with 74ALS574



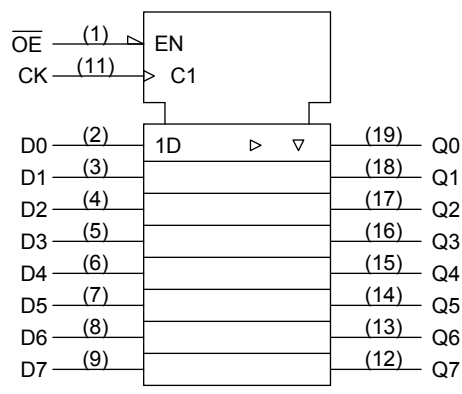
#### Weight

|                      |                 |
|----------------------|-----------------|
| SOP20-P-300-1.27A    | : 0.22 g (typ.) |
| TSSOP20-P-0044-0.65A | : 0.08 g (typ.) |
| VSSOP20-P-0030-0.50  | : 0.03 g (typ.) |

Pin Assignment



IEC Logic Symbol

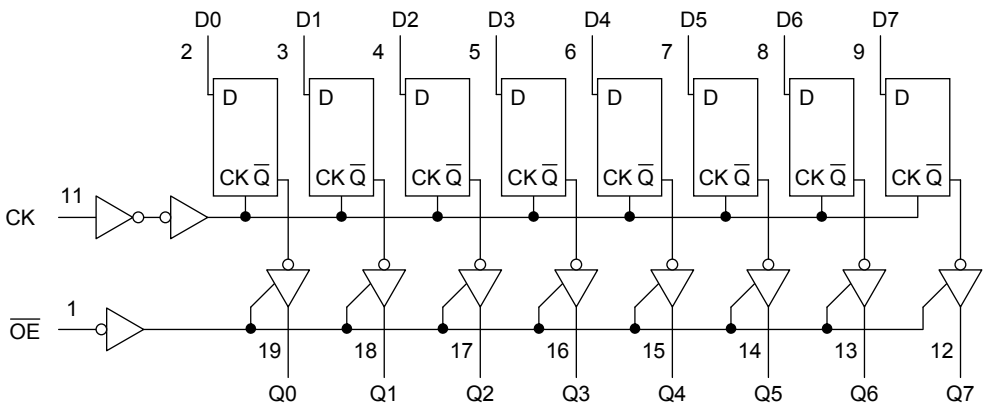


Truth Table

| Inputs |    |   | Output         |
|--------|----|---|----------------|
| OE     | CK | D |                |
| H      | X  | X | Z              |
| L      |    | X | Q <sub>n</sub> |
| L      |    | L | L              |
| L      |    | H | H              |

X: Don't care  
Z: High impedance  
Q<sub>n</sub>: No change

System Diagram



## Absolute Maximum Ratings (Note)

| Characteristics             | Symbol    | Rating                 | Unit |
|-----------------------------|-----------|------------------------|------|
| Supply voltage range        | $V_{CC}$  | -0.5 to 7.0            | V    |
| DC input voltage            | $V_{IN}$  | -0.5 to 7.0            | V    |
| DC output voltage           | $V_{OUT}$ | -0.5 to $V_{CC} + 0.5$ | V    |
| Input diode current         | $I_{IK}$  | -20                    | mA   |
| Output diode current        | $I_{OK}$  | $\pm 20$               | mA   |
| DC output current           | $I_{OUT}$ | $\pm 25$               | mA   |
| DC $V_{CC}$ /ground current | $I_{CC}$  | $\pm 75$               | mA   |
| Power dissipation           | $P_D$     | 180                    | mW   |
| Storage temperature         | $T_{stg}$ | -65 to 150             | °C   |

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

## Operating Ranges (Note)

| Characteristics          | Symbol    | Rating                                                                    | Unit |
|--------------------------|-----------|---------------------------------------------------------------------------|------|
| Supply voltage           | $V_{CC}$  | 2.0 to 5.5                                                                | V    |
| Input voltage            | $V_{IN}$  | 0 to 5.5                                                                  | V    |
| Output voltage           | $V_{OUT}$ | 0 to $V_{CC}$                                                             | V    |
| Operating temperature    | $T_{opr}$ | -40 to 85                                                                 | °C   |
| Input rise and fall time | $dt/dv$   | 0 to 100 ( $V_{CC} = 3.3 \pm 0.3$ V)<br>0 to 20 ( $V_{CC} = 5 \pm 0.5$ V) | ns/V |

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

## Electrical Characteristics

## DC Characteristics

| Characteristics                     | Symbol          | Test Condition                                                                                    |                                                    | Ta = 25°C               |                               |        | Ta =<br>-40 to 85°C           |                               | Unit                          |     |
|-------------------------------------|-----------------|---------------------------------------------------------------------------------------------------|----------------------------------------------------|-------------------------|-------------------------------|--------|-------------------------------|-------------------------------|-------------------------------|-----|
|                                     |                 |                                                                                                   |                                                    | V <sub>CC</sub> (V)     | Min                           | Typ.   | Max                           | Min                           |                               | Max |
| High-level input voltage            | V <sub>IH</sub> | —                                                                                                 |                                                    | 2.0<br>3.0 to 5.5       | 1.50<br>V <sub>CC</sub> × 0.7 | —<br>— | —<br>—                        | 1.50<br>V <sub>CC</sub> × 0.7 | —<br>—                        | V   |
| Low-level input voltage             | V <sub>IL</sub> | —                                                                                                 |                                                    | 2.0<br>3.0 to 5.5       | —<br>—                        | —<br>— | 0.50<br>V <sub>CC</sub> × 0.3 | —<br>—                        | 0.50<br>V <sub>CC</sub> × 0.3 | V   |
| High-level output voltage           | V <sub>OH</sub> | V <sub>IN</sub><br>= V <sub>IH</sub> or V <sub>IL</sub>                                           | I <sub>OH</sub> = -50 μA                           | 2.0                     | 1.9                           | 2.0    | —                             | 1.9                           | —                             | V   |
|                                     |                 |                                                                                                   |                                                    | 3.0                     | 2.9                           | 3.0    | —                             | 2.9                           | —                             |     |
|                                     |                 |                                                                                                   |                                                    | 4.5                     | 4.4                           | 4.5    | —                             | 4.4                           | —                             |     |
|                                     |                 |                                                                                                   | I <sub>OH</sub> = -4 mA<br>I <sub>OH</sub> = -8 mA | 3.0<br>4.5              | 2.58<br>3.94                  | —<br>— | —<br>—                        | 2.48<br>3.80                  | —<br>—                        |     |
| Low-level output voltage            | V <sub>OL</sub> | V <sub>IN</sub><br>= V <sub>IH</sub> or V <sub>IL</sub>                                           |                                                    | I <sub>OL</sub> = 50 μA | 2.0                           | —      | 0.0                           | 0.1                           | —                             | 0.1 |
|                                     |                 |                                                                                                   | 3.0                                                |                         | —                             | 0.0    | 0.1                           | —                             | 0.1                           |     |
|                                     |                 |                                                                                                   | 4.5                                                |                         | —                             | 0.0    | 0.1                           | —                             | 0.1                           |     |
|                                     |                 |                                                                                                   | I <sub>OL</sub> = 4 mA<br>I <sub>OL</sub> = 8 mA   | 3.0<br>4.5              | —<br>—                        | —<br>— | 0.36<br>0.36                  | —<br>—                        | 0.44<br>0.44                  |     |
| 3-state output<br>off-state current | I <sub>OZ</sub> | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub><br>V <sub>OUT</sub> = V <sub>CC</sub> or GND |                                                    | 5.5                     | —                             | —      | ±0.25                         | —                             | ±2.50                         | μA  |
| Input leakage<br>current            | I <sub>IN</sub> | V <sub>IN</sub> = 5.5 V or GND                                                                    |                                                    | 0 to 5.5                | —                             | —      | ±0.1                          | —                             | ±1.0                          | μA  |
| Quiescent supply<br>current         | I <sub>CC</sub> | V <sub>IN</sub> = V <sub>CC</sub> or GND                                                          |                                                    | 5.5                     | —                             | —      | 4.0                           | —                             | 40.0                          | μA  |

Timing Requirements (input: t<sub>r</sub> = t<sub>f</sub> = 3 ns)

| Characteristics          | Symbol             | Test Condition |   | Ta = 25°C           |      | Ta = -40 to 85°C | Unit |
|--------------------------|--------------------|----------------|---|---------------------|------|------------------|------|
|                          |                    |                |   | V <sub>CC</sub> (V) | Typ. | Limit            |      |
| Minimum pulse width (CK) | t <sub>w</sub> (H) | —              | — | 3.3 ± 0.3           | —    | 5.0              | ns   |
|                          | t <sub>w</sub> (L) |                |   | 5.0 ± 0.5           | —    | 5.0              |      |
| Minimum set-up time      | t <sub>s</sub>     | —              | — | 3.3 ± 0.3           | —    | 3.5              | ns   |
|                          |                    |                |   | 5.0 ± 0.5           | —    | 3.5              |      |
| Minimum hold time        | t <sub>h</sub>     | —              | — | 3.3 ± 0.3           | —    | 1.5              | ns   |
|                          |                    |                |   | 5.0 ± 0.5           | —    | 1.5              |      |

## AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$ )

| Characteristics                  | Symbol            | Test Condition        |                     |                     | Ta = 25°C |      |      | Ta =<br>−40 to 85°C |      | Unit |
|----------------------------------|-------------------|-----------------------|---------------------|---------------------|-----------|------|------|---------------------|------|------|
|                                  |                   |                       | V <sub>CC</sub> (V) | C <sub>L</sub> (pF) | Min       | Typ. | Max  | Min                 | Max  |      |
| Propagation delay time<br>(CK-Q) | t <sub>pLH</sub>  | —                     | 3.3 ± 0.3           | 15                  | —         | 8.5  | 13.2 | 1.0                 | 15.5 | ns   |
|                                  |                   |                       |                     | 50                  | —         | 11.0 | 16.7 | 1.0                 | 19.0 |      |
|                                  | t <sub>pHL</sub>  |                       | 5.0 ± 0.5           | 15                  | —         | 5.6  | 8.6  | 1.0                 | 10.0 |      |
|                                  |                   |                       |                     | 50                  | —         | 7.1  | 10.6 | 1.0                 | 12.0 |      |
| 3-state output enable time       | t <sub>pZL</sub>  | R <sub>L</sub> = 1 kΩ | 3.3 ± 0.3           | 15                  | —         | 8.2  | 12.8 | 1.0                 | 15.0 | ns   |
|                                  |                   |                       |                     | 50                  | —         | 10.7 | 16.3 | 1.0                 | 18.5 |      |
|                                  | t <sub>pZH</sub>  |                       | 5.0 ± 0.5           | 15                  | —         | 5.9  | 9.0  | 1.0                 | 10.5 |      |
|                                  |                   |                       |                     | 50                  | —         | 7.4  | 11.0 | 1.0                 | 12.5 |      |
| 3-state output disable time      | t <sub>pLZ</sub>  | R <sub>L</sub> = 1 kΩ | 3.3 ± 0.3           | 50                  | —         | 11.0 | 15.0 | 1.0                 | 17.0 | ns   |
|                                  | t <sub>pHZ</sub>  |                       | 5.0 ± 0.5           | 50                  | —         | 7.1  | 10.1 | 1.0                 | 11.5 |      |
| Maximum clock frequency          | f <sub>max</sub>  | —                     | 3.3 ± 0.3           | 15                  | 80        | 125  | —    | 65                  | —    | MHz  |
|                                  |                   |                       |                     | 50                  | 50        | 75   | —    | 45                  | —    |      |
|                                  |                   |                       | 5.0 ± 0.5           | 15                  | 130       | 180  | —    | 110                 | —    |      |
|                                  |                   |                       |                     | 50                  | 85        | 115  | —    | 75                  | —    |      |
| Output to output skew            | t <sub>osLH</sub> | (Note 1)              | 3.3 ± 0.3           | 50                  | —         | —    | 1.5  | —                   | 1.5  | ns   |
|                                  | t <sub>osHL</sub> |                       | 5.0 ± 0.5           | 50                  | —         | —    | 1.0  | —                   | 1.0  |      |
| Input capacitance                | C <sub>IN</sub>   | —                     |                     |                     | —         | 4    | 10   | —                   | 10   | pF   |
| Output capacitance               | C <sub>OUT</sub>  | —                     |                     |                     | —         | 6    | —    | —                   | —    | pF   |
| Power dissipation capacitance    | C <sub>PD</sub>   | (Note 2)              |                     |                     | —         | 28   | —    | —                   | —    | pF   |

Note 1: Parameter guaranteed by design.

$$t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|$$

Note 2: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per F/F)}$$

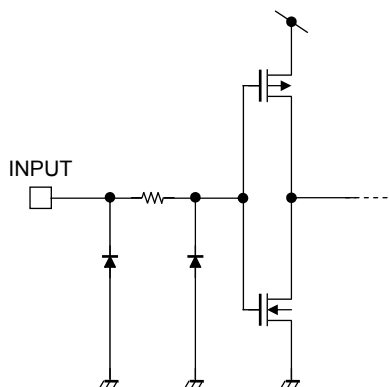
And the total C<sub>PD</sub> when n pcs. of latch operate can be gained by the following equation:

$$C_{PD (total)} = 20 + 8 \cdot n$$

## Noise Characteristics (input: $t_r = t_f = 3 \text{ ns}$ )

| Characteristics                              | Symbol           | Test Condition         | Ta = 25°C           |      |      | Unit |
|----------------------------------------------|------------------|------------------------|---------------------|------|------|------|
|                                              |                  |                        | V <sub>CC</sub> (V) | Typ. | Max  |      |
| Quiet output maximum dynamic V <sub>OL</sub> | V <sub>OLP</sub> | C <sub>L</sub> = 50 pF | 5.0                 | 0.8  | 1.0  | V    |
| Quiet output minimum dynamic V <sub>OL</sub> | V <sub>OLV</sub> | C <sub>L</sub> = 50 pF | 5.0                 | -0.8 | -1.0 | V    |
| Minimum high level dynamic input voltage     | V <sub>IHD</sub> | C <sub>L</sub> = 50 pF | 5.0                 | —    | 3.5  | V    |
| Maximum low level dynamic input voltage      | V <sub>ILD</sub> | C <sub>L</sub> = 50 pF | 5.0                 | —    | 1.5  | V    |

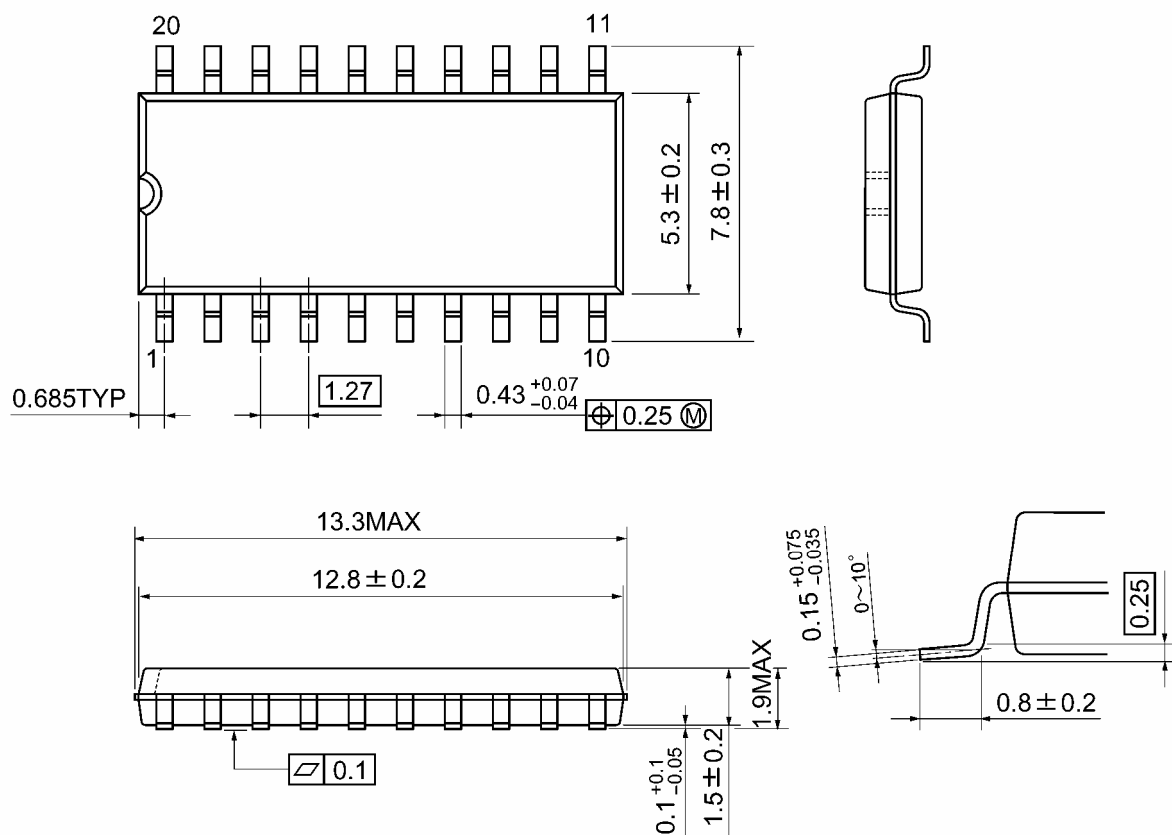
## Input Equivalent Circuit



## Package Dimensions

SOP20-P-300-1.27A

Unit: mm

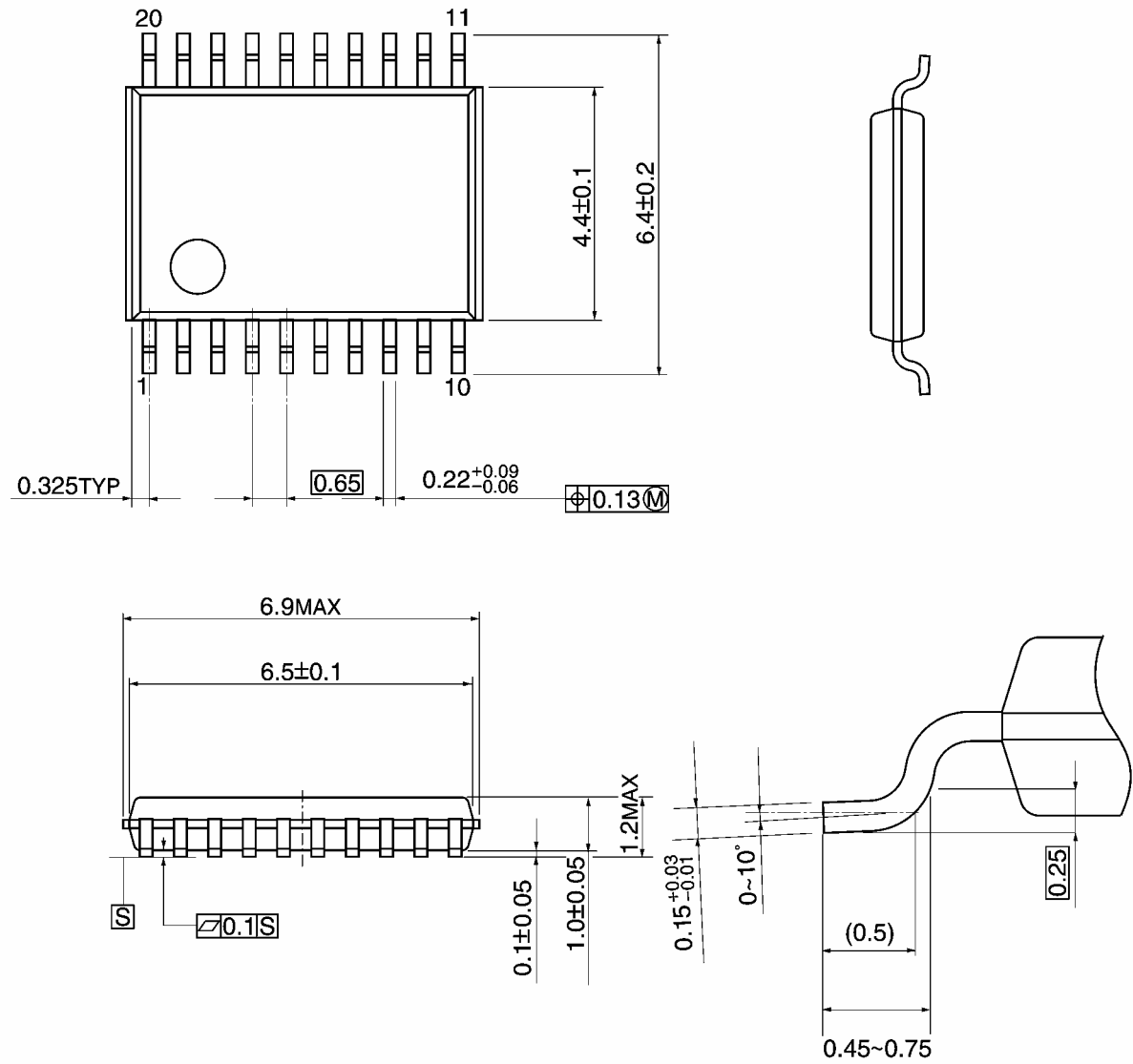


Weight: 0.22 g (typ.)

Package Dimensions

TSSOP20-P-0044-0.65A

Unit: mm

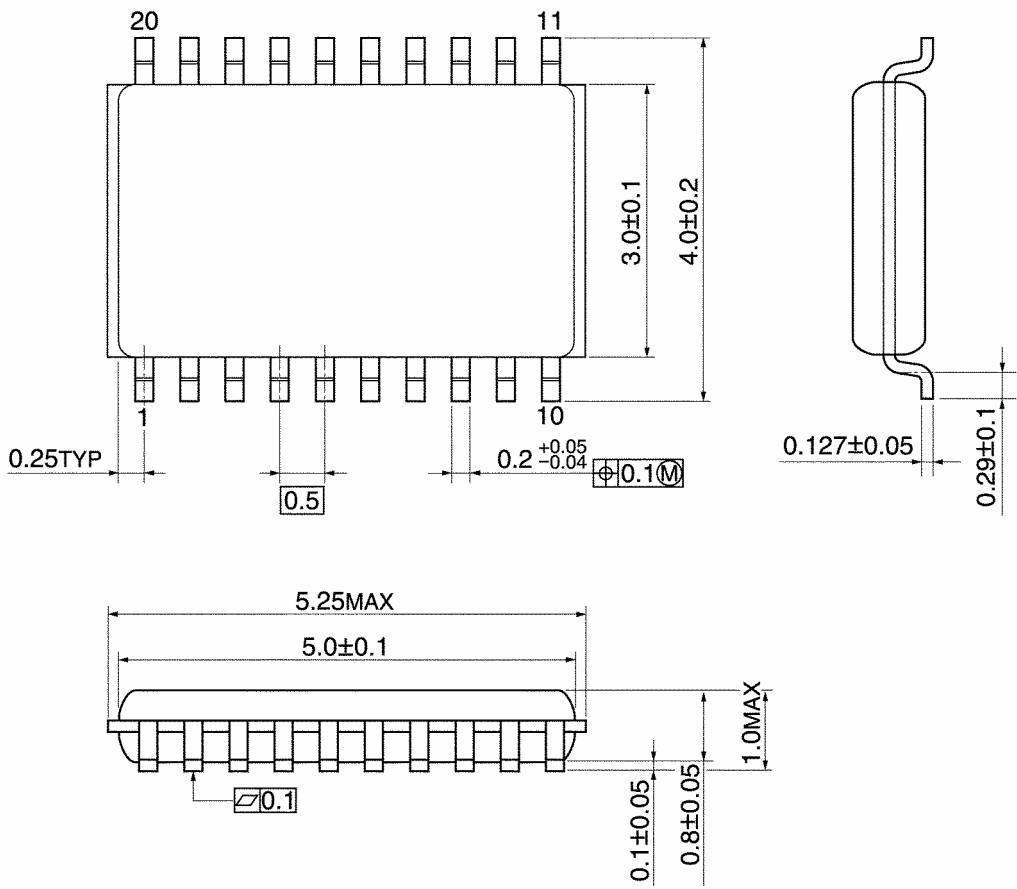


Weight: 0.08 g (typ.)

Package Dimensions

VSSOP20-P-0030-0.50

Unit: mm



Weight: 0.03 g (typ.)

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20070701-EN GENERAL

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